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History AutoCAD version 1.0 was released on November 5, 1986. This version was developed by a team of three engineers headed by Rod Morrison. The first version of AutoCAD was a very basic desktop app that made it easier for users to design mechanical parts and facilities. This was a big first step for Autodesk, since it was the first time an individual had been able to effectively use CAD. The first version of AutoCAD 1.0 allowed users to sketch and edit features in three dimensions and draw shapes. It also included a primitive camera tool and basic layer management.

The company later added the ability to rotate, scale, and move features using the mouse, as well as export and import. The earliest versions were unable to import and export DXF files. Another important milestone was the introduction of AutoCAD Mechanical (Autodesk's first CAD package that included a milling system). The base model was made for producing architectural-style industrial steel structural components. AutoCAD Mechanical was a fast and low-cost method of creating steel components because it was based on a detailed parametric model. As such, it was a breakthrough in the way that CAD was used for designing metal structures. AutoCAD Mechanical was designed by John H. Marston. The base model was acquired by another company, and the development team left Autodesk. AutoCAD Mechanical was then integrated into AutoCAD in April 1994, but the original name is still used by many users. The concept of parametric design AutoCAD is a parametric design system. AutoCAD has a parametric modeling system for creating curves, solids, surfaces, and 3D objects. The parametric modeling system is based on modeling geometry using splines. The splines are based on a

curve that can be drawn using standard line segments. The curve can also be modified to reflect changes in the object's dimension (size or position) after it has been drawn. Unlike a pencil and paper design, parametric modeling creates a file that can be edited and reused in a subsequent design phase. The parametric modeling system can be used in two ways: Drawing model – In this case, the user draws the line or curve by hand and later creates a parametric object (of the same shape and size) in the modeling window. Editing model – In this case, the user changes the curve in the modeling window and then saves the changes to create an edited model. Both methods

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Content compression and decompression : In AutoCAD's native file formats, document objects are compressed using the DEFLATE algorithm in the DSC1 format. Any additional or custom objects are saved separately. References Further reading External links Autodesk's AutoCAD homepage Autodesk Exchange for AutoCAD plugins and add-ons

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TaqMan® assay. (XLSX 10 kb) AE : Apnea ASP : Apnea syndrome BE : Bradycardia CPR : Cardiopulmonary resuscitation EtCO~2~ : End-tidal carbon dioxide *GSTM1* : Glutathione S-transferase Mu *GSTT1* : Glutathione S-transferase Theta *MT-CO2* : Cytochrome c oxidase subunit II NOH : Normal hypoxia OAH : Overtriage hypoxia a1d647c40b

AutoCAD X64

The present invention is related to a chemical vapor deposition method for fabricating a high-k/metal gate (HKMG) structure. More particularly, the present invention is directed to a method of forming a HKMG structure that is suitable for use in advanced complimentary metal oxide semiconductor (CMOS) technologies. Scaling of integrated circuit technology is limited by the need to maintain control over the leakage current through the gate oxide layer of field effect transistors (FETs). Scaling of the technology is being driven primarily by the continuing reduction in the gate oxide thickness. However, further reduction in the thickness of the gate oxide layer will lead to a dramatic increase in the leakage current through the gate oxide layer. One approach that has been proposed to address this challenge is the so-called high-k/metal gate (HKMG) technology. HKMG allows the use of the traditional polysilicon/gate dielectric/polysilicon (poly/SiO2/poly) stack configuration, while providing very high, substantially constant oxide integrity. As shown in FIG. 1, in the HKMG approach the high-k

gate dielectric layer 8 is used as a replacement for the thin gate dielectric layer 4 which is conventionally made from SiO2. The gate dielectric layer 8 comprises a high-k material such as hafnium oxide (HfO2), aluminum oxide (Al2O3), yttrium oxide (Y2O3), zirconium oxide (ZrO2), tantalum oxide (Ta2O5), etc. The high-k dielectric layer 8 is placed between the high-k gate electrode layer 6 and the polysilicon/metal layer 2 that is used as the floating gate. The polysilicon/metal gate/high-k gate dielectric/high-k gate electrode is similar to the standard poly/SiO2/poly gate, with the exception that the high-k gate electrode is used instead of the conventional poly electrode. The use of a high-k/metal gate dielectric (HK/metal gate dielectric) eliminates the need for a direct contact between the high-k gate dielectric and the polysilicon in the conventional gate structure. The HKMG approach has also been proposed for the formation of floating gate structures. The floating gate structures are widely used in flash memory devices. In such devices, the floating gate typically needs to be isolated from the polysil

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System Requirements For AutoCAD:

Minimum: OS: Windows XP SP3 / Vista SP2 / Windows 7 SP1 Processor: Intel Pentium III 603 or higher, AMD K6-2+ / AMD K6-III+, PowerPC G4 or higher Memory: 1 GB RAM Video: Intel AGP or AMD VESA 2x16 Video Card, 256 MB VRAM DirectX: Version 9.0c Hard Drive: 11 GB Additional Notes: Must be able to download 650 MB. Click to expand...

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